
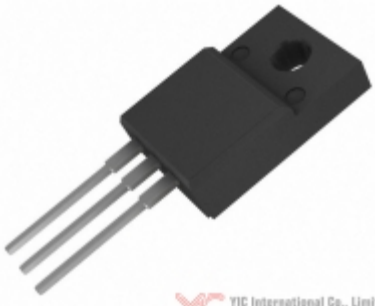





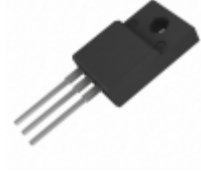
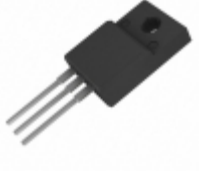

	<h2>SIHF12N50C-E3</h2>
	<p>Hersteller-Teilenummer: SIHF12N50C-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 500V 12A TO-220</p> <p>Datenblätter:  SIHF12N50C-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 7920 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIHF12N50C-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 500V 12A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	7920 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3 Full Pack
Supplier Device-Gehäuse	TO-220 Full Pack
Verlustleistung (max)	36W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12A (Tc)
Rds On (Max) @ Id, Vgs	555 mOhm @ 4A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	48nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1375pF @ 25V
Verpackung	Tube



















































SIHF12N50C-E3 ist neu im Original. Suche SIHF12N50C-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIHF12N50C-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIHF12N50C-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIHF10N40D-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 400V 10A TO-220 FPAK</p>	 <p>SIHF12N50C Vishay SIHF12N50C Vishay</p>	 <p>SIHF12N50C TK12A50D Toshiba Semiconductor and Storage SIHF12N50C TK12A50D TOSHIBA</p>	 <p>SIHF12N60E TK12A60 Toshiba Semiconductor and Storage SIHF12N60E TK12A60 TOSHIBA</p>
 <p>SIHF12N60E Vishay Precision Group SIHF12N60E VISHAY</p>	 <p>SIHF12N60E-E3 Vishay / Siliconix MOSFET N-CH 600V 12A TO220 FULLP</p>	 <p>SIHF10N40D-E3 Vishay / Siliconix MOSFET N-CH 400V 10A TO-220 FPAK</p>	 <p>SIHF12N50C. VB SIHF12N50C. VB</p>

heiße Teile

Mehr

 SIHF12N50C-E3	 SIHF12N50C-E3	 SIHF12N50E	 SIHF12N60E	 SIHF12N60E-GE3
 SIHB12N60E-GE3	 SIHB12N65E	 SIHB15N50E	 SIHB15N60E-GE3	 SIHB15N60E-GE3
 SIHB15N65E	 SIHB16N50C	 SIHB16N50CTR-E3	 SIHB18N60E	 SIHB33N60E-GE3
 SIHB33N60E-GE3	 SIHD3N50D-GE3	 SIHD3N50D-GE3	 SIHD7N60E-GE3	 SIHD7N60E-GE3
 SIHF10N40D	 SIHF10N40D-E3	 SIHF10N40D-E3	 SIHF12N50C	 SIHF12N50C-E3
 SIHF12N60E	 SIHF12N60E-E3	 SIHF12N60E-E3	 SIHF12N60E-GE3	 SIHF12N60E-GE3
 SIHF12N60E-GE3	 SIHF12N65E	 SIHF15N60E	 SIHF15N60E-E3	 SIHF15N60E-E3
 SIHF15N60E-EG3	 SIHF15N60E-GE3	 SIHF15N60E-GE3	 SIHF16N50C	 SIHF16N50C-E3
 SIHF16N50C-E3	 SIHF18N50C-E3	 SIHF18N50C-E3	 SIHF18N50D	 SIHF18N50D-E3
 SIHF18N50D-E3	 SIHF22N65E-GE3	 SIHF22N65E-GE3	 SIHF510S	 SIHF520S

Contact us: Info@Y-IC.com

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